MBR4045WTG

Switch Mode Power Rectifier

Features and Benefits

- Low Forward Voltage
- Low Power Loss/High Efficiency
- High Surge Capacity
- 175°C Operating Junction Temperature
- 40 A Total (20 A Per Diode Leg)
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

Applications

- Power Supply Output Rectification
- Power Management
- Instrumentation

Mechanical Characteristics

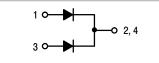
- Case: Epoxy, Molded
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- ESD Rating: Human Body Model 3B Machine Model C

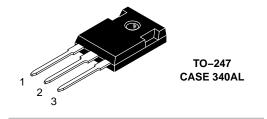


ON Semiconductor®

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 40 AMPERES, 45 VOLTS





MARKING DIAGRAM



| MBR4045WT | = Device Code |
|-----------|---------------------|
| А | = Assembly Location |

| : | = Assembly | Location |
|---|------------|----------|
| | | |

= Year

Y

G

WW

- = Work Week
 - = Pb-Free Package

ORDERING INFORMATION

| Device | Package | Shipping |
|------------|---------------------|---------------|
| MBR4045WTG | TO–247 (Pb–Free) | 30 Units/Rail |

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MBR4045WTG

MAXIMUM RATINGS

| Rating | Symbol | Max | Unit |
|--|--|-------------|------|
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 45 | V |
| Average Rectified Forward Current(Rated V_R , $T_C = 125^{\circ}C$)Per DiodePer Device | I _{F(AV)} | 20 40 | A |
| Peak Repetitive Forward Current, (Rated V _R , Square Wave, 20 kHz, $T_C = 90^{\circ}C$) Per Diode | I _{FRM} | 40 | A |
| Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz) | I _{FSM} | 400 | A |
| Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz) | I _{RRM} | 2.0 | A |
| Storage Temperature Range | T _{stg} | -65 to +175 | °C |
| Operating Junction Temperature (Note 1) | TJ | -65 to +175 | °C |
| Peak Surge Junction Temperature (Forward Current Applied) | T _{J(pk)} | 175 | °C |
| Voltage Rate of Change | dv/dt | 10,000 | V/µs |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient: $dP_D/dT_J < 1/R_{\theta JA}$.

THERMAL CHARACTERISTICS

| Characteristic | Conditions | Symbol | Max | Unit |
|---|------------|-----------------------|------|------|
| Maximum Thermal Resistance, Junction-to-Case | Min. Pad | $R_{	extsf{	heta}JC}$ | 1.4 | °C/W |
| Maximum Thermal Resistance, Junction-to-Ambient | Min. Pad | R_{\thetaJA} | 50.1 | °C/W |

ELECTRICAL CHARACTERISTICS

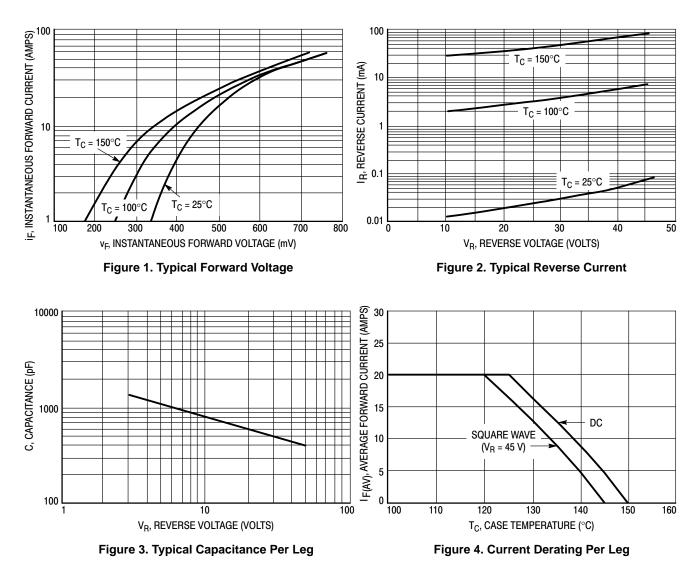
| Characteristic | Symbol | Min | Typical | Max | Unit |
|--|----------------|-----|------------------------------|------------------------------|------|
| Instantaneous Forward Voltage (Note 2) @ $I_F = 20$ Amps, $T_J = 25^{\circ}C$ @ $I_F = 20$ Amps, $T_J = 125^{\circ}C$ @ $I_F = 40$ Amps, $T_J = 25^{\circ}C$ @ $I_F = 40$ Amps, $T_J = 125^{\circ}C$ | VF | | 0.52 0.47 0.65 0.63 | 0.70 0.60 0.80 0.75 | V |
| Instantaneous Reverse Current (Note 2) @ Rated DC Voltage, T _J = 25°C @ Rated DC Voltage, T _J = 100°C | I _R | | 0.09 7.5 | 1.0 50 | mA |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

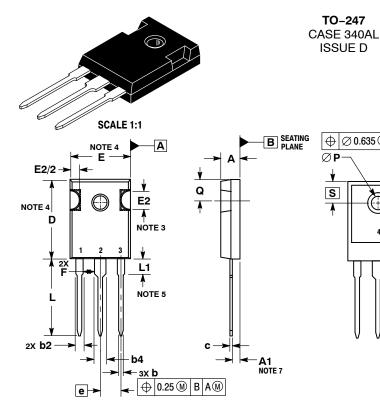
2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle < 2.0%

MBR4045WTG

TYPICAL ELECTRICAL CHARACTERISTICS



semi



 $\oplus | \emptyset 0.635 \otimes | B | A \otimes$ ØP NOTE 6 ۷ S Ŧ 4 4

TO-247

ISSUE D

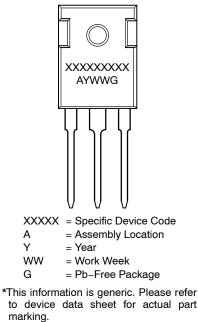
DATE 17 MAR 2017

NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. SLOT REQUIRED, NOTCH MAY BE ROUNDED. 1
- 2. 3.
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED 0.13 PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREME OF THE PLASTIC BODY.
- LEAD FINISH IS UNCONTROLLED IN THE REGION DEFINED BY 5.
- L1. 6.
- ⊘P SHALL HAVE A MAXIMUM DRAFT ANGLE OF 1.5° TO THE TOP OF THE PART WITH A MAXIMUM DIAMETER OF 3.91.
- 7. DIMENSION A1 TO BE MEASURED IN THE REGION DEFINED

| BY L1. | | | | |
|--------|-------------|-------|--|--|
| | MILLIMETERS | | | |
| DIM | MIN | MAX | | |
| Α | 4.70 | 5.30 | | |
| A1 | 2.20 | 2.60 | | |
| b | 1.07 | 1.33 | | |
| b2 | 1.65 | 2.35 | | |
| b4 | 2.60 | 3.40 | | |
| C | 0.45 | 0.68 | | |
| D | 20.80 | 21.34 | | |
| Е | 15.50 | 16.25 | | |
| E2 | 4.32 | 5.49 | | |
| е | 5.45 | BSC | | |
| F | 2.655 | | | |
| L | 19.80 | 20.80 | | |
| L1 | 3.81 | 4.32 | | |
| Ρ | 3.55 | 3.65 | | |
| Q | 5.40 | 6.20 | | |
| S | 6.15 BSC | | | |

GENERIC **MARKING DIAGRAM***



Pb-Free indicator, "G" or microdot " .", may or may not be present.

| DOCUMENT NUMBER: | 98AON16119F | Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. | | |
|------------------|-------------|---|-------------|--|
| DESCRIPTION: | TO-247 | | PAGE 1 OF 1 | |

onsemi and ONSEMi. are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products herein. special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>